

## Special Issue

# Advances in GaN Materials

### Message from the Guest Editor

The fundamental breakthrough of high-quality GaN material growth on sapphire substrate has led to the great success of highly efficient InGaN-based blue/white light-emitting diodes (LEDs), which has been recognized by the 2014 Nobel Prize for Physics. Recently, new progress has been made in the field of (Al, Ga, In)N material growth and characterization, including Al-rich Al(Ga)N and In-rich In(Ga)N film and heterostructures, free-standing GaN and AlN substrates, as well as III-nitride semiconductor nanostructures, which are enabling the fabrication and commercialization of high ultraviolet (UV)/green/yellow/red LEDs, laser diodes, and high electron mobility transistors with a great prospect in a wide array of applications. This Special Issue will focus on the recent advances in GaN materials with feature articles covering the topics of free-standing GaN and AlN substrates growth and device homoepitaxy, Al-rich Al(Ga)N and In-rich In(Ga)N film and heterostructure growth, GaN heteroepitaxy with novel buffer like graphene, GaN-based material and device growth on Si substrates, III-nitride semiconductor nanostructure growth, etc.

### Guest Editor

Dr. Qian Sun

Suzhou Institute of Nano-tech and Nano-bionics, Chinese Academy of Sciences, Suzhou, China

### Deadline for manuscript submissions

closed (10 April 2022)



## Materials

an Open Access Journal  
by MDPI

Impact Factor 3.2  
CiteScore 6.4  
Indexed in PubMed



[mdpi.com/si/88609](https://mdpi.com/si/88609)

*Materials*  
Editorial Office  
MDPI, Grosspeteranlage 5  
4052 Basel, Switzerland  
Tel: +41 61 683 77 34  
[materials@mdpi.com](mailto:materials@mdpi.com)

[mdpi.com/journal/  
materials](https://mdpi.com/journal/materials)





# Materials

---

an Open Access Journal  
by MDPI

---

Impact Factor 3.2  
CiteScore 6.4  
Indexed in PubMed



[mdpi.com/journal/  
materials](https://mdpi.com/journal/materials)



## About the Journal

### Message from the Editor-in-Chief

*Materials* (ISSN 1996-1944) was launched in 2008. The journal covers twenty-five comprehensive topics: biomaterials, energy materials, advanced composites, advanced materials characterization, porous materials, manufacturing processes and systems, advanced nanomaterials and nanotechnology, smart materials, thin films and interfaces, catalytic materials, carbon materials, materials chemistry, materials physics, optics and photonics, corrosion, construction and building materials, materials simulation and design, electronic materials, advanced and functional ceramics and glasses, metals and alloys, soft matter, polymeric materials, quantum materials, mechanics of materials, green materials, general. *Materials* provides a unique opportunity to contribute high quality articles and to take advantage of its large readership.

---

### Editor-in-Chief

Prof. Dr. Maryam Tabrizian

1. Department of Biomedical Engineering, Faculty of Medicine and Health Sciences, McGill University, Montreal, QC H3A 2B6, Canada
2. Faculty of Dentistry and Oral Health Sciences, McGill University, 3640 Rue University, Montreal, QC H3A 0C7, Canada

---

### Author Benefits

#### Open Access:

free for readers, with article processing charges (APC) paid by authors or their institutions.

#### High Visibility:

indexed within Scopus, SCIE (Web of Science), PubMed, PMC, Ei Compendex, CaPlus / SciFinder, Inspec, Astrophysics Data System, and other databases.

#### Journal Rank:

JCR - Q2 (Metallurgy and Metallurgical Engineering) /  
CiteScore - Q1 (Condensed Matter Physics)